

SMC Plastic-Encapsulate Diodes

Super Fast Recovery Rectifier Diodes

Features

- $I_{F(AV)}$ 3A
- V_{RRM} 200V-600V
- High surge current capability
- Polarity: Color band denotes cathode

Applications

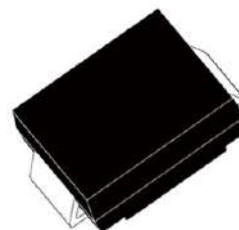
- Rectifier

Marking

- MURS3X0

X : From 2 to 6

SMC



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	KMURS3			
				20C	30C	40C	60C
Repetitive Peak Reverse Voltage	V_{RRM}	V		200	300	400	600
Maximum RMS Voltage	V_{RMS}	V		140	210	280	420
Average Forward Current	$I_{F(AV)}$	A	60Hz Half-sine wave, Resistance load, $T_a=120^\circ\text{C}$	3.0			
Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz Half-sine wave, 1 cycle, $T_a=25^\circ\text{C}$	100			
Operation Junction and Storage Temperature Range	T_J, T_{STG}	$^\circ\text{C}$		-55 ~ +175			

Electrical Characteristics ($T=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition		KMURS3			
					20C	30C	40C	60C
Peak Forward Voltage	V _F	V	I _{FM} =3.0A		0.875	1.25		
Reverse recovery time	t _{rr}	ns	I _F =0.5A, I _R =1.0A I _{rr} =0.25A		25	50		
Peak Reverse Current	I _{RRM1}	μA	V _{RM} =V _{RRM}	Ta =25 °C	3			
	Ta =100 °C			100				
Thermal Resistance(Typical)	R _{θJ-A}	°C/W	Between junction and ambient		55			
	R _{θJ-L}		Between junction and terminal		12			

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

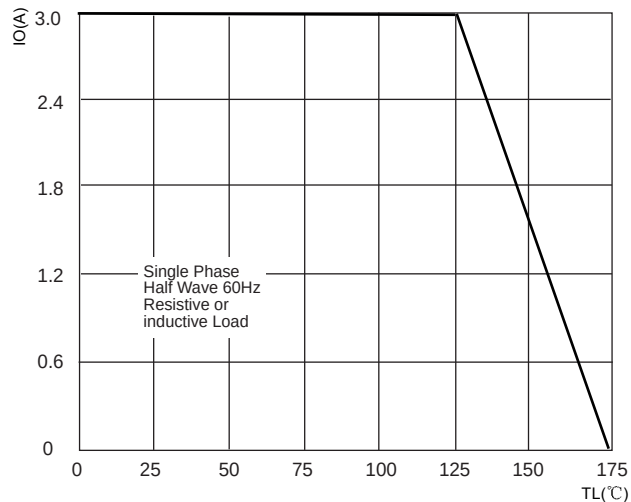


FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

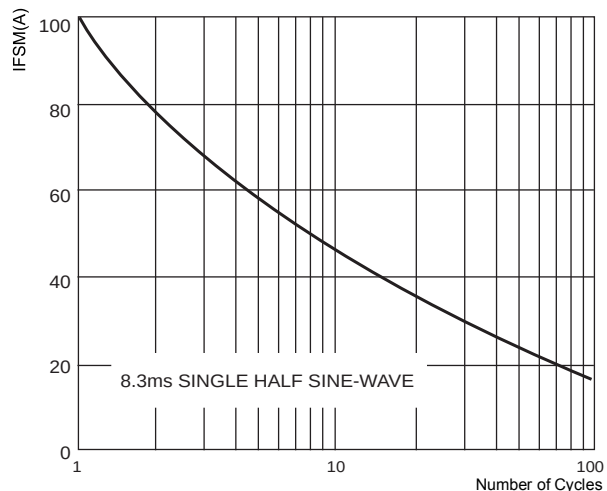


FIG.3: TYPICAL FORWARD CHARACTERISTICS

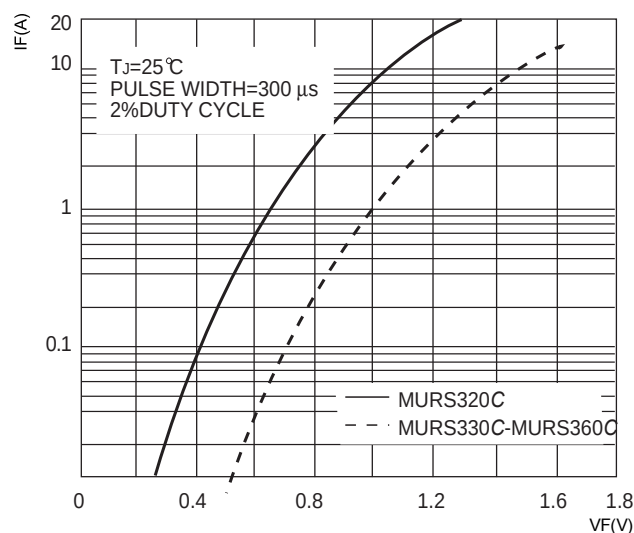


FIG.4: TYPICAL REVERSE CHARACTERISTICS

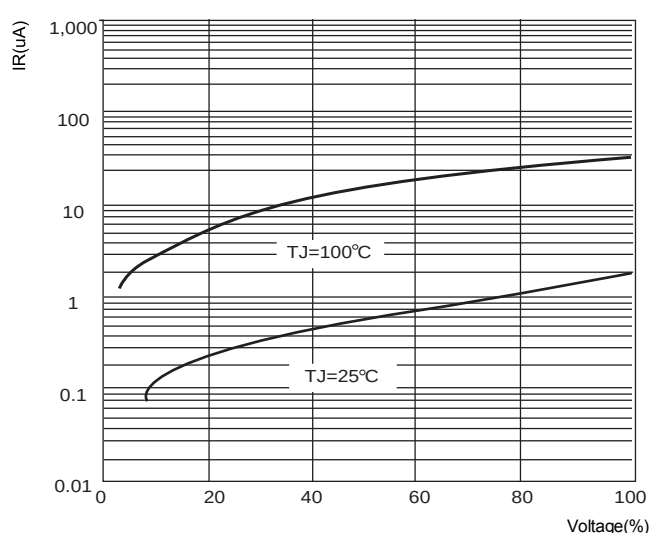
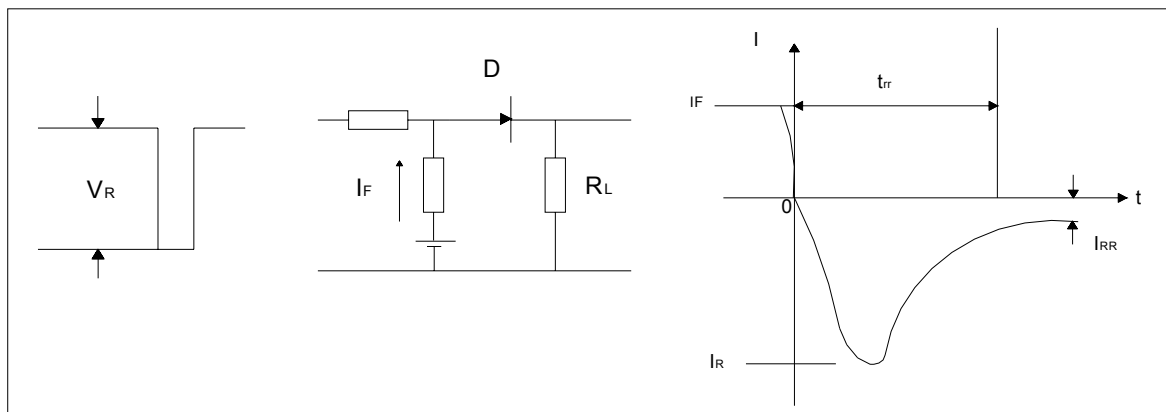
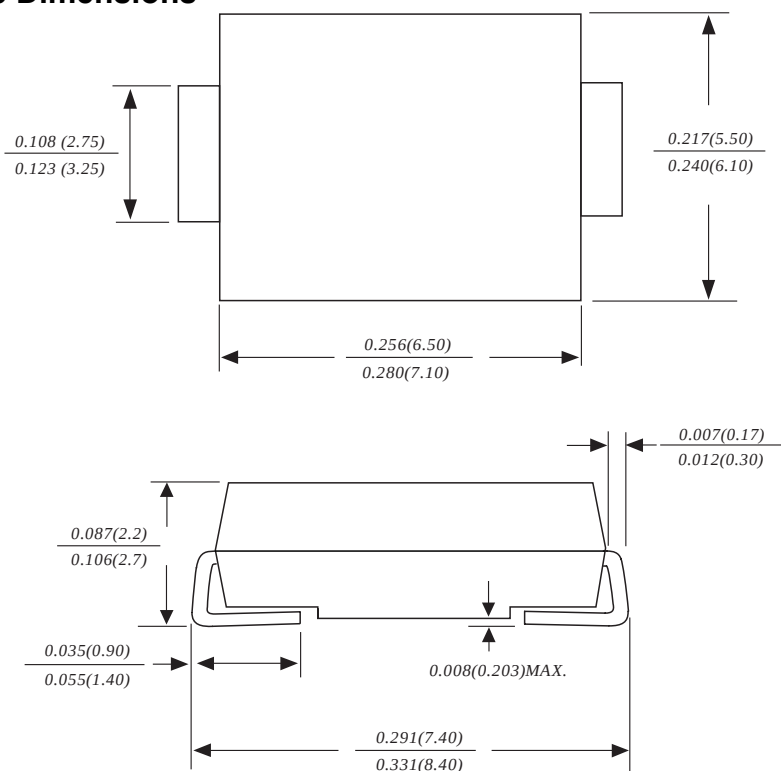


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

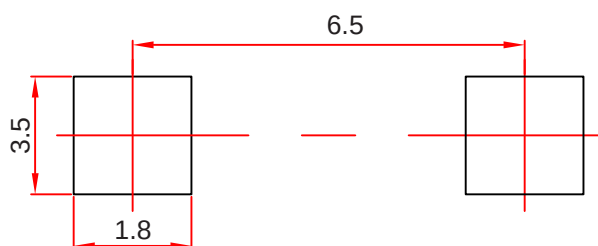


SMC Package Outline Dimensions



Dimensions in inches and (millimeters)

SMCG Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

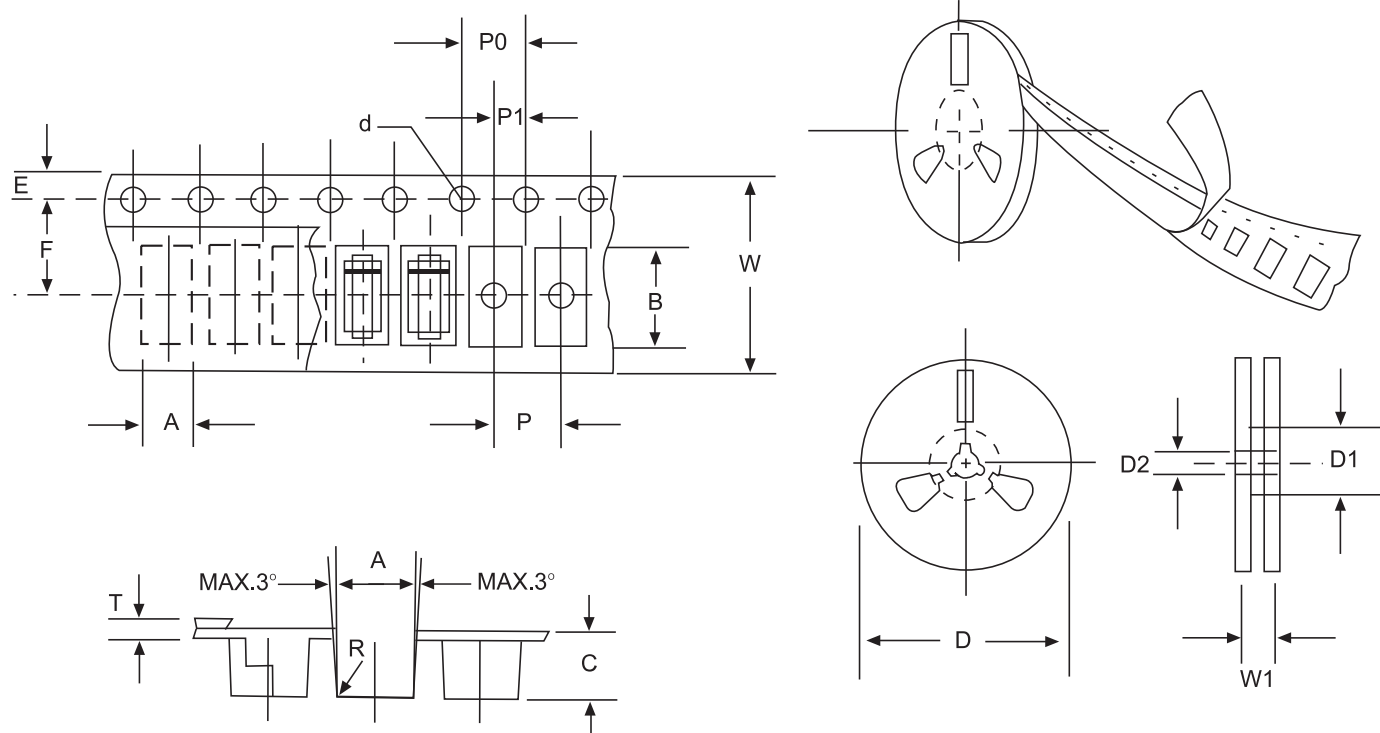


FIG:CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING

ITEM	SYMBOL	SMC mm(inch)
Carrier width	A	6.05±0.1(0.238±0.004)
Carrier length	B	8.31±0.1(0.327±0.004)
Carrier depth	C	2.70±0.1(0.106±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	330±2.0(13±0.079)
Reel inner diameter	D1	75 ±1.0 (2.95 ±0.039)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Strocket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	7.65±0.05(0.301±0.002)
Punch hole pitch	P	8.0±0.1(0.315±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Totall tape thickness	T	0.3±0.1(0.012±0.004)
Tape width	W	16.0±0.2(0.630±0.008)
Reel width	W1	24.0±2.0(0.945±0.079)

NOTE:Devices are packed in accordance with EIA standard RS-481-A and specification given above.